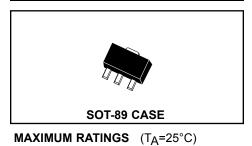


## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER





## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CXSH-4 type is a Schottky barrier rectifier mounted in an epoxy molded case using a metal to silicon junction to yield low forward voltage drop. This device utilizes a single chip with anode connections made to PIN 1 and PIN 3.

	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	40	V
DC Blocking Voltage	VR	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Forward Current	ΙO	1.0	А
Peak Forward Surge Current (8.3ms, Non-Rep.) Operating and Storage	IFSM	10	А
Junction Temperature	T <sub>J</sub> ,T <sub>stg</sub>	-65 to +150	°C

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I <sub>R</sub>	V <sub>R</sub> =40V		1.0	mA
IR	V <sub>R</sub> =40V, T <sub>A</sub> =100°C		10	mA
VF	I <sub>F</sub> =1.0A		0.55	V

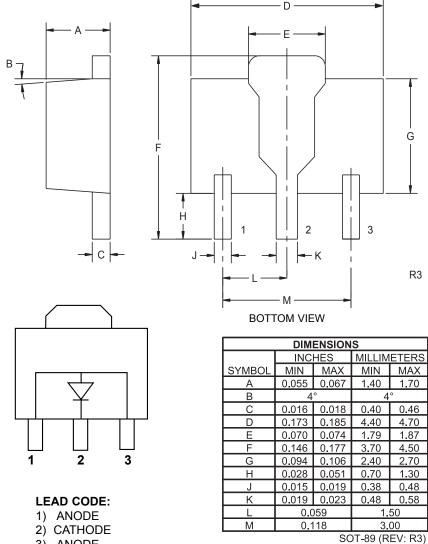
R3 (19-December 2001)



CXSH-4

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

SOT-89 CASE - MECHANICAL OUTLINE



<sup>3)</sup> ANODE

PIN 2 IS COMMON TO THE TAB

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